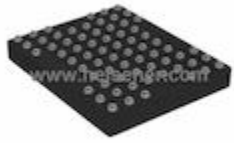


TC58BYG1S3HBAI6 Information


For Reference Only

Part Number [TC58BYG1S3HBAI6](#)
Manufacturer Toshiba Semiconductor and Storage
Category Integrated Circuits (ICs)
[Memory](#)
Description IC EEPROM 2GBIT 25NS 67VFBGA
Package 67-VFBGA
 For the pricing/inventory/lead time, please contact us
 Website: <https://www.heisener.com>
 E-mail: salesdept@heisener.com


[Request a Quote](#)
Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.


TC58BYG1S3HBAI6 Specifications

Manufacturer Part Number	TC58BYG1S3HBAI6
Manufacturer	Toshiba Semiconductor and Storage
Category	Integrated Circuits (ICs) Memory
Package	67-VFBGA
Series	Benand?
Memory Type	Non-Volatile
Memory Format	EEPROM
Technology	EEPROM - NAND
Memory Size	2Gb (256M x 8)
Memory Interface	Parallel
Clock Frequency	-
Write Cycle Time - Word, Page	25ns
Access Time	25ns
Voltage - Supply	1.7 V ~ 1.95 V
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	67-VFBGA
Supplier Device Package	67-VFBGA (6.5x8)

[Report errors?](#)

TC58BYG1S3HBAI6 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

TC58BYG1S3HBAI6 Payment Methods



TC58BYG1S3HBAI6 Shipping Methods



If you have any question about TC58BYG1S3HBAI6, please do not hesitate to contact us!

Website: <https://www.heisener.com>

E-mail: salesdept@heisener.com